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**General Description:**

Pn infrared gallium arsenide light emitting diode optically coupled to an npn silicon photo darlington transistor, 1500 v min isolation voltage, 0.25 w power dissipation, -55 to 100 degrees c operating temp range, six-pin plastic case, 0.350 in. Maximum l, 0.310 in. Maximum w, 0.160 in. Maximum h

**Specification Data:**

80131-release 6464 professional/industrial association specification

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

Yes - demil/mli

**Fiig:**

A23900